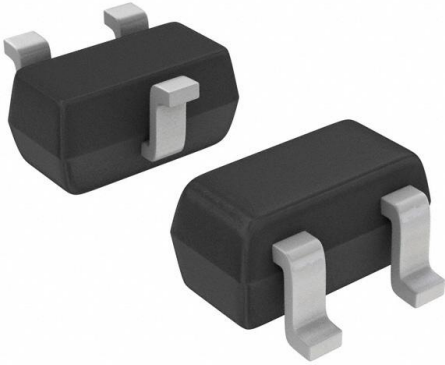


# DTA123JET1 Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	DTA123JET1-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	DTA123JET1
Description	TRANS PREBIAS PNP 50V 0.1A SC75
Detailed Description	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased 50 V 100 mA 200 mW Surface Mount SC-75, SOT-416



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.

## Purchase and inquiry

Manufacturer Product Number:

DTA123JET1

Series:

-

Transistor Type:

PNP - Pre-Biased

Voltage - Collector Emitter Breakdown (Max):

50 V

Resistor - Emitter Base (R2):

47 kOhms

Vce Saturation (Max) @ Ib, Ic:

250mV @ 300μA, 10mA

Power - Max:

200 mW

Package / Case:

SC-75, SOT-416

Base Product Number:

DTA123

Manufacturer:

onsemi

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Resistor - Base (R1):

2.2 kOhms

DC Current Gain (hFE) (Min) @ Ic, Vce:

80 @ 5mA, 10V

Current - Collector Cutoff (Max):

500nA

Mounting Type:

Surface Mount

Supplier Device Package:

SC-75, SOT-416

## Environmental & Export classification

RoHS Status:

RoHS non-compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

# DTA114EET1 Series, SDTA114EET1 Series

Preferred Devices

## Bias Resistor Transistors

### PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-75/SOT-416 package which is designed for low power surface mount applications.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SC-75/SOT-416 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- Pb-Free Packages are Available\*

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current	I <sub>C</sub>	100	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



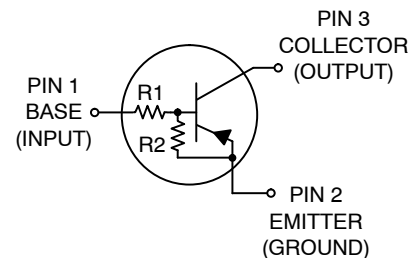
ON Semiconductor®

<http://onsemi.com>

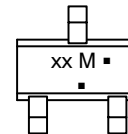
### PNP SILICON BIAS RESISTOR TRANSISTORS



SC-75 (SOT-416)  
CASE 463  
STYLE 1



#### MARKING DIAGRAM



- xx = Specific Device Code  
xx = (Refer to page 4)
- M = Date Code\*
- = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**DTA114EET1 Series, SDTA114EET1 Series****THERMAL CHARACTERISTICS**

Rating	Symbol	Value	Unit
Total Device Dissipation, FR-4 Board (Note 1) @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	200 1.6	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	$^\circ\text{C}/\text{W}$
Total Device Dissipation, FR-4 Board (Note 2) @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	400	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

- FR-4 @ Minimum Pad.
- FR-4 @  $1.0 \times 1.0$  Inch Pad.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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**OFF CHARACTERISTICS**

Collector-Base Cutoff Current ( $V_{CB} = 50\text{ V}, I_E = 0$ )	$I_{CBO}$	-	-	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE} = 50\text{ V}, I_B = 0$ )	$I_{CEO}$	-	-	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0\text{ V}, I_C = 0$ )	$I_{EBO}$				mAdc
DTA114EET1		-	-	0.5	
DTA124EET1		-	-	0.2	
DTA144EET1		-	-	0.1	
DTA114YET1, SDTA114YET1		-	-	0.2	
DTA114TET1		-	-	0.9	
DTA143TET1		-	-	1.9	
DTA123EET1		-	-	2.3	
DTA143EET1		-	-	1.5	
DTA143ZET1		-	-	0.18	
DTA124XET1		-	-	0.13	
DTA123JET1		-	-	0.2	
DTA115EET1		-	-	0.05	
DTA144WET1		-	-	0.13	
Collector-Base Breakdown Voltage ( $I_C = 10\ \mu\text{A}, I_E = 0$ )	$V_{(BR)CBO}$	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 3) ( $I_C = 2.0\text{ mA}, I_B = 0$ )	$V_{(BR)CEO}$	50	-	-	Vdc

- Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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**ON CHARACTERISTICS** (Note 4)

DC Current Gain ( $V_{CE} = 10\text{ V}, I_C = 5.0\text{ mA}$ )	$h_{FE}$				-
DTA114EET1		35	60	-	
DTA124EET1		60	100	-	
DTA144EET1		80	140	-	
DTA114YET1, SDTA114YET1		80	140	-	
DTA114TET1		160	250	-	
DTA143TET1		160	250	-	
DTA123EET1		8.0	15	-	
DTA143EET1		15	27	-	
DTA143ZET1		80	140	-	
DTA124XET1		80	130	-	
DTA123JET1		80	140	-	
DTA115EET1		80	150	-	
DTA144WET1		80	140	-	

**DTA114EET1 Series, SDTA114EET1 Series****ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)**ON CHARACTERISTICS** (Note 4)

Collector-Emitter Saturation Voltage ( $I_C = 10\text{ mA}$ , $I_E = 0.3\text{ mA}$ ) ( $I_C = 10\text{ mA}$ , $I_B = 5\text{ mA}$ ) DTA123EET1 ( $I_C = 10\text{ mA}$ , $I_B = 1\text{ mA}$ ) DTA114TET1/DTA143TET1 DTA143ZET1/DTA124XET1 DTA143EET1	$V_{CE(sat)}$	–	–	0.25	Vdc
Output Voltage (on) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 2.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) DTA114EET1 DTA124EET1 DTA114YET1, SDTA114YET1 DTA114TET1 DTA143TET1 DTA123EET1 DTA143EET1 DTA143ZET1 DTA124XET1 DTA123JET1 ( $V_{CC} = 5.0\text{ V}$ , $V_B = 3.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) DTA144EET1 ( $V_{CC} = 5.0\text{ V}$ , $V_B = 5.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) DTA115EET1 ( $V_{CC} = 5.0\text{ V}$ , $V_B = 4.0\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) DTA144WET1	$V_{OL}$	–	–	0.2	Vdc
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	
		–	–	0.2	

5. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (continued)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>ON CHARACTERISTICS</b> (Note 6)					
Output Voltage (off) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.25\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) DTA114TET1 DTA143TET1 DTA123EET1 DTA143EET1	$V_{OH}$	4.9	–	–	Vdc
Input Resistor DTA114EET1 DTA124EET1 DTA144EET1 DTA114YET1, SDTA114YET1 DTA114TET1 DTA143TET1 DTA123EET1 DTA143EET1 DTA143ZET1 DTA124XET1 DTA123JET1 DTA115EET1 DTA144WET1	$R_1$	7.0 15.4 32.9 7.0 7.0 3.3 1.5 3.3 3.3 3.3 15.4 1.54 70 32.9	10 22 47 10 10 4.7 2.2 4.7 4.7 4.7 22 2.2 100 47	13 28.6 61.1 13 13 6.1 2.9 6.1 6.1 6.1 28.6 2.86 130 61.1	$\text{k}\Omega$
Resistor Ratio DTA114EET1/DTA124EET1 DTA144EET1/DTA115EET1 DTA114YET1, SDTA114YET1 DTA114TET1/DTA143TET1 DTA123EET1/DTA143EET1 DTA143ZET1 DTA124XET1 DTA123JET1 DTA144WET1	$R_1/R_2$	– 0.8 0.17 – 0.8 0.055 0.38 0.038 1.7	– 1.0 0.21 – 1.0 0.1 0.47 0.047 2.1	– 1.2 0.25 – 1.2 0.185 0.56 0.056 2.6	–

6. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%

**DTA114EET1 Series, SDTA114EET1 Series****ORDERING INFORMATION AND RESISTOR VALUES**

Device	Marking	R1 (K)	R2 (K)	Package	Shipping†
DTA114EET1	6A	10	10	SC-75	3,000 Tape & Reel
DTA114EET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA124EET1	6B	22	22	SC-75	3,000 Tape & Reel
DTA124EET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA144EET1	6C	47	47	SC-75	3,000 Tape & Reel
DTA144EET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA114YET1	6D	10	47	SC-75	3,000 Tape & Reel
DTA114YET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
SDTA114YET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA114TET1	6E	10	∞	SC-75	3,000 Tape & Reel
DTA114TET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA143TET1	6F	4.7	∞	SC-75	3,000 Tape & Reel
DTA143TET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA123EET1	6H	2.2	2.2	SC-75	3,000 Tape & Reel
DTA123EET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA143EET1	43	4.7	4.7	SC-75	3,000 Tape & Reel
DTA143EET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA143ZET1	6K	4.7	47	SC-75	3,000 Tape & Reel
DTA143ZET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA124XET1	6L	22	47	SC-75	3,000 Tape & Reel
DTA124XET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA123JET1	6M	2.2	47	SC-75	3,000 Tape & Reel
DTA123JET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA115EET1	6N	100	100	SC-75	3,000 Tape & Reel
DTA115EET1G				SC-75 (Pb-Free)	3,000 Tape & Reel
DTA144WET1	6P	47	22	SC-75	3,000 Tape & Reel
DTA144WET1G				SC-75 (Pb-Free)	3,000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### DTA114EET1 Series, SDTA114EET1 Series

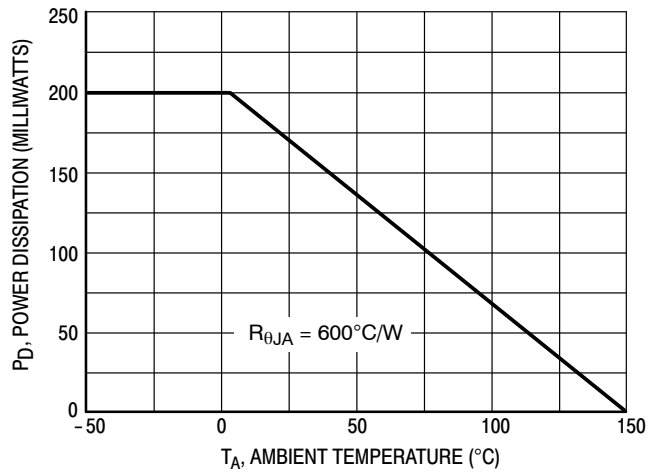


Figure 1. Derating Curve

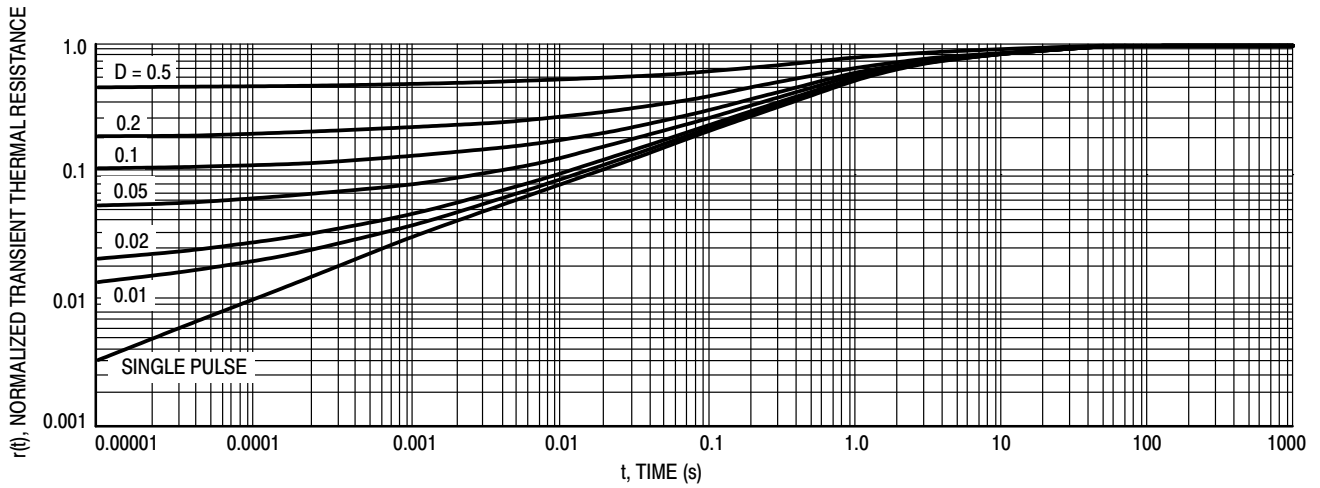
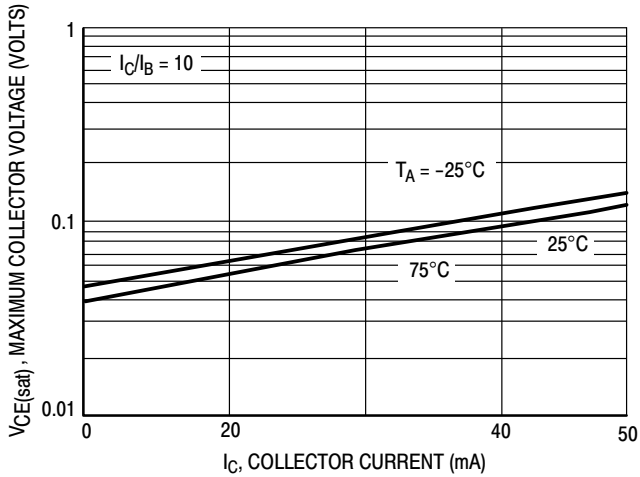


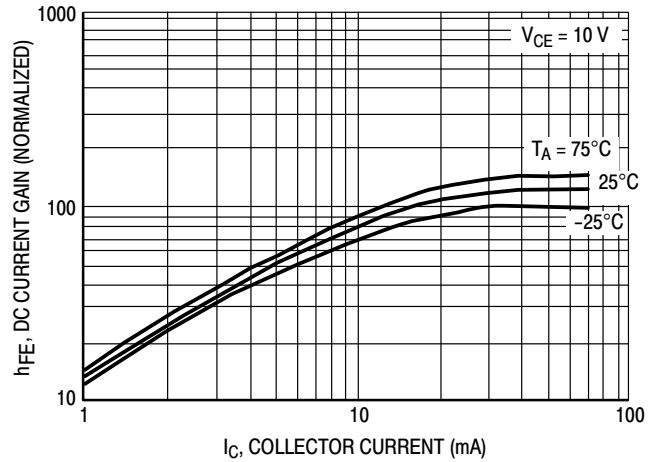
Figure 2. Normalized Thermal Response

**DTA114EET1 Series, SDTA114EET1 Series**

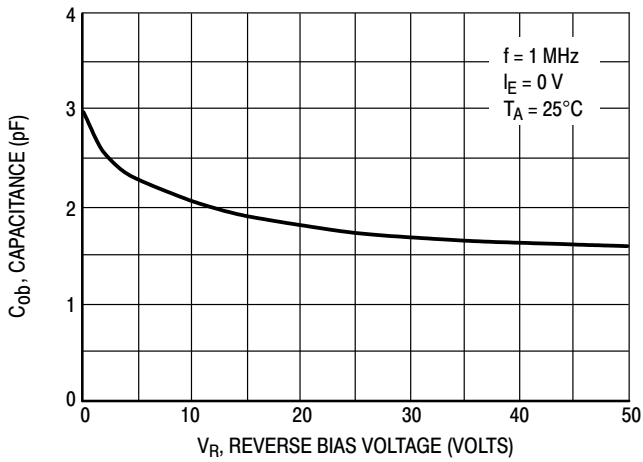
**TYPICAL ELECTRICAL CHARACTERISTICS - DTA114EET1**



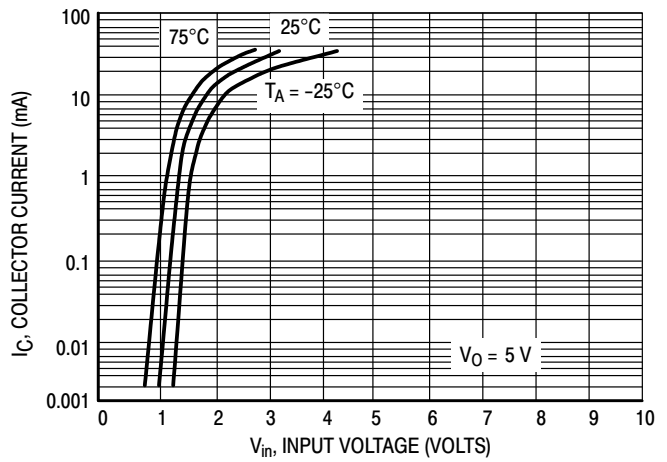
**Figure 3.  $V_{CE(sat)}$  versus  $I_C$**



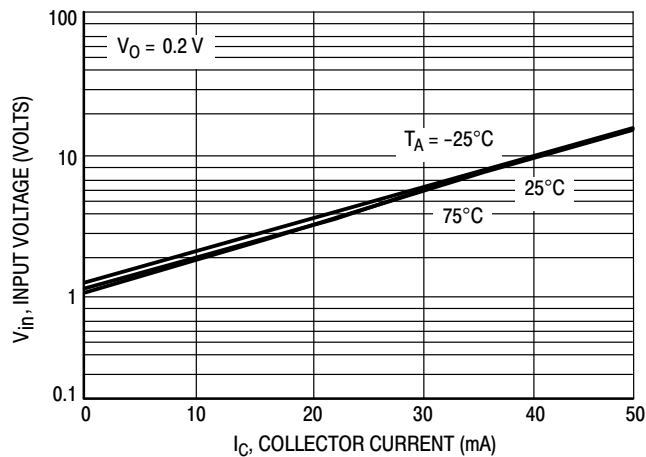
**Figure 4. DC Current Gain**



**Figure 5. Output Capacitance**



**Figure 6. Output Current versus Input Voltage**

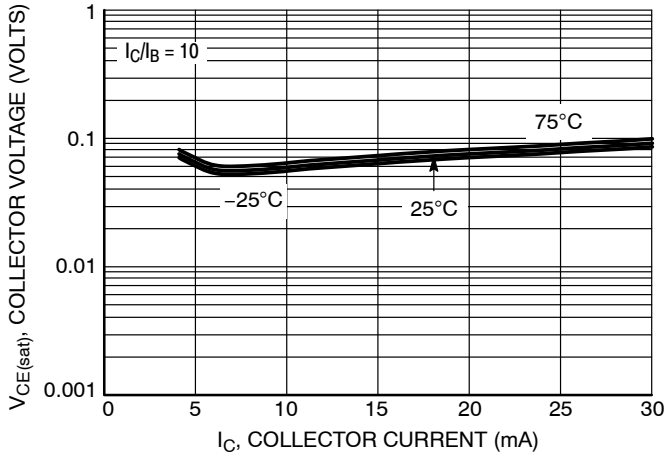


**Figure 7. Input Voltage versus Output Current**

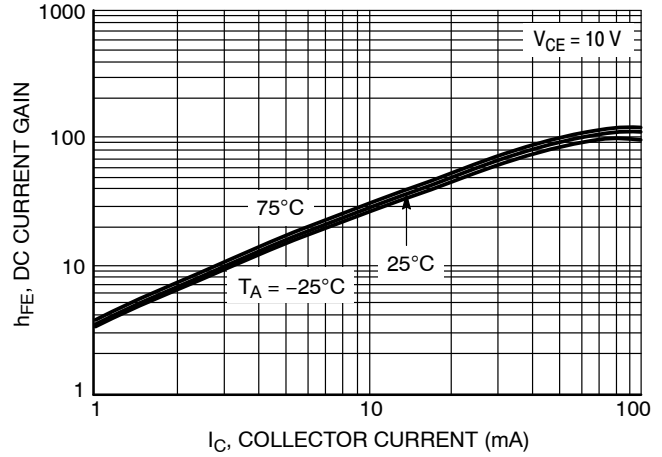


**DTA114EET1 Series, SDTA114EET1 Series**

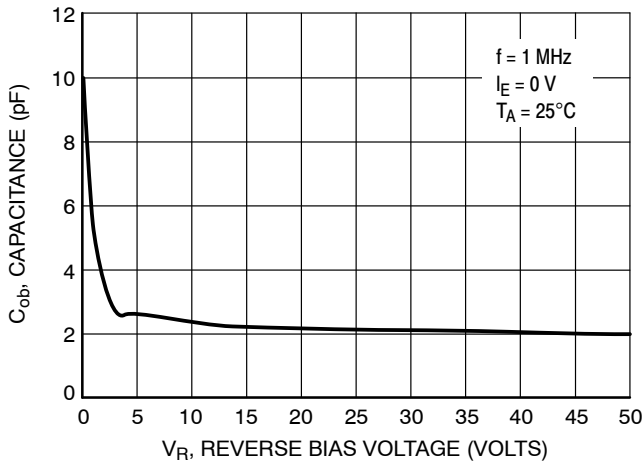
**TYPICAL ELECTRICAL CHARACTERISTICS - DTA123EET1**



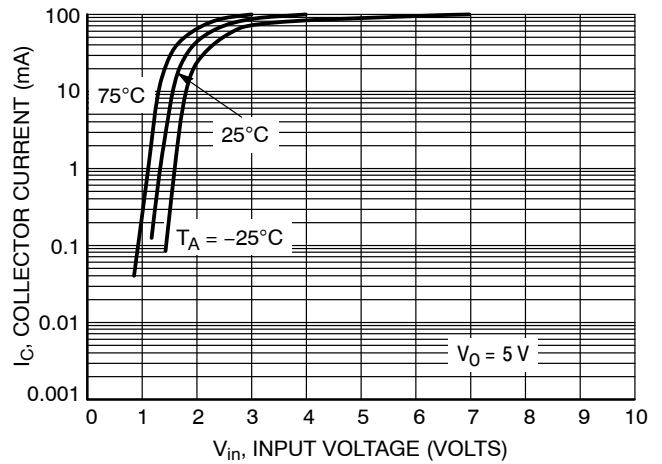
**Figure 8.  $V_{CE(sat)}$  versus  $I_C$**



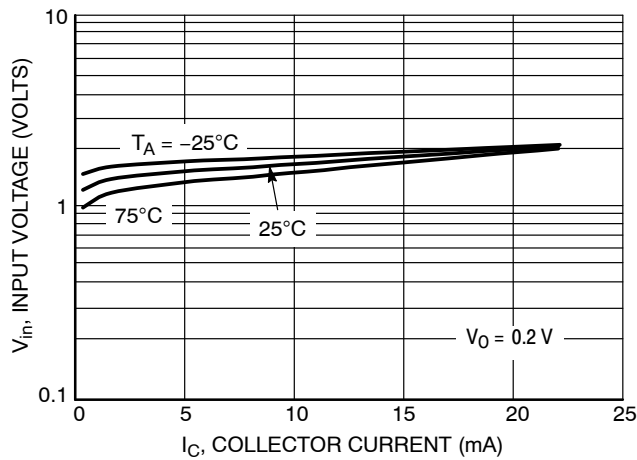
**Figure 9. DC Current Gain**



**Figure 10. Output Capacitance**



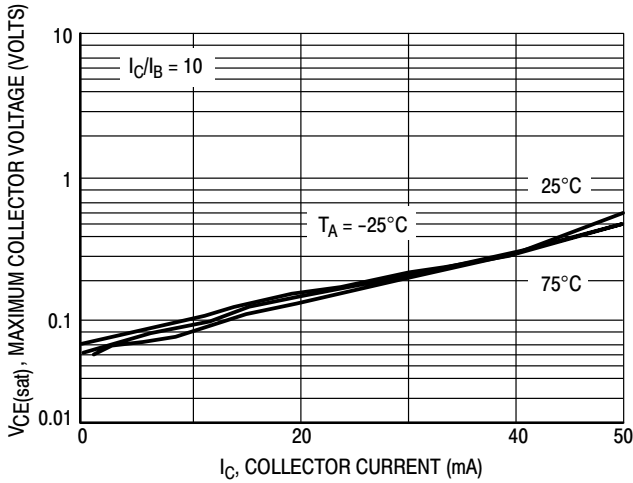
**Figure 11. Output Current versus Input Voltage**



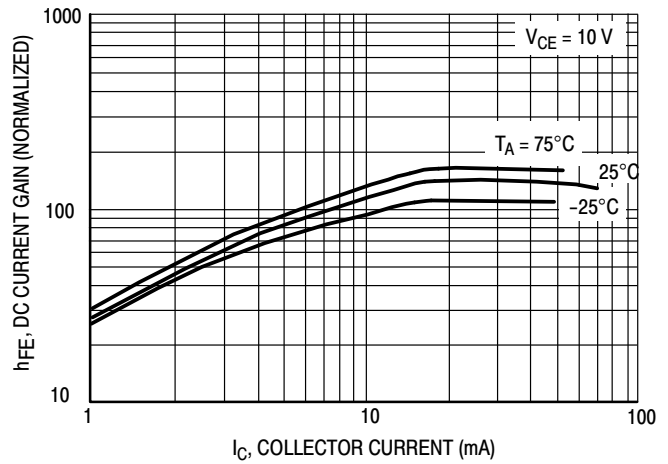
**Figure 12. Input Voltage versus Output Current**

**DTA114EET1 Series, SDTA114EET1 Series**

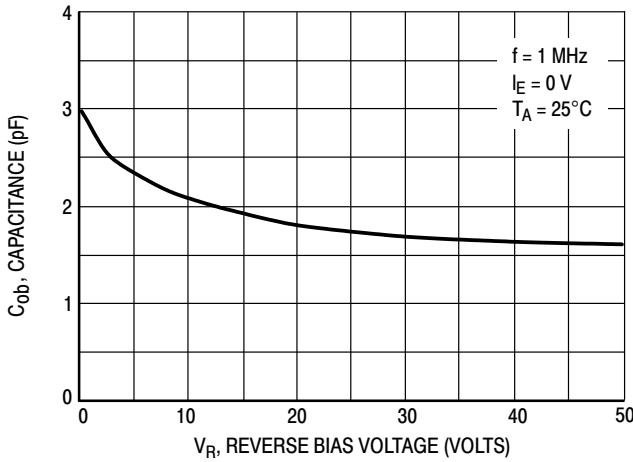
**TYPICAL ELECTRICAL CHARACTERISTICS - DTA124EET1**



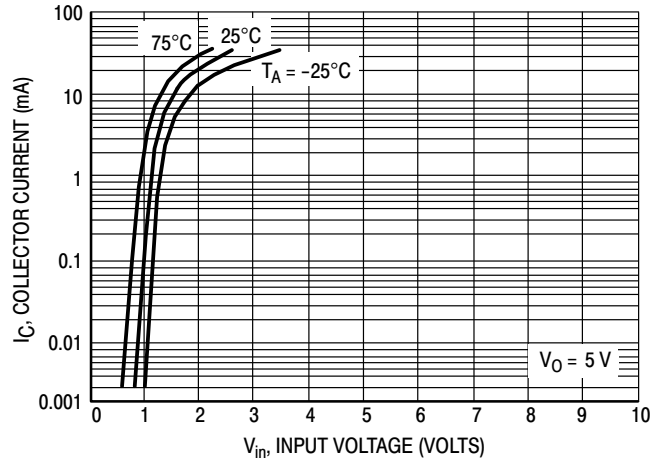
**Figure 13.  $V_{CE(sat)}$  versus  $I_C$**



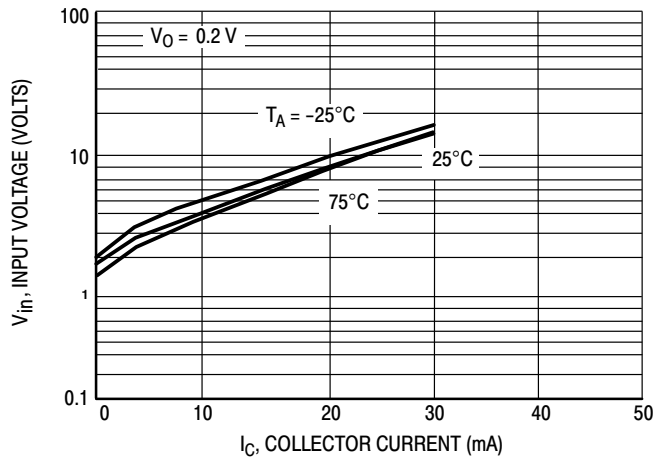
**Figure 14. DC Current Gain**



**Figure 15. Output Capacitance**



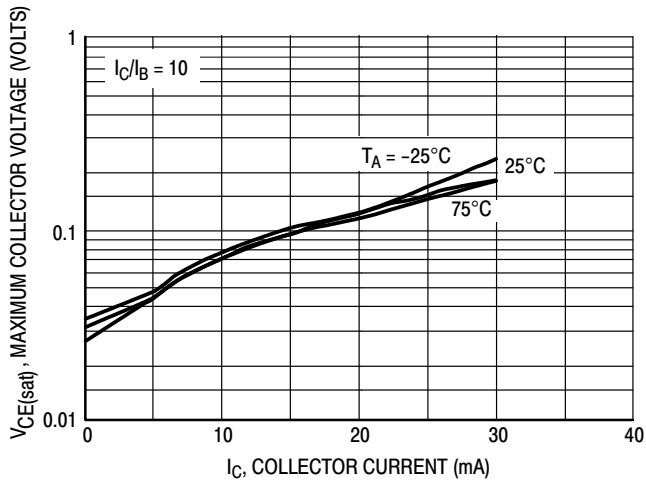
**Figure 16. Output Current versus Input Voltage**



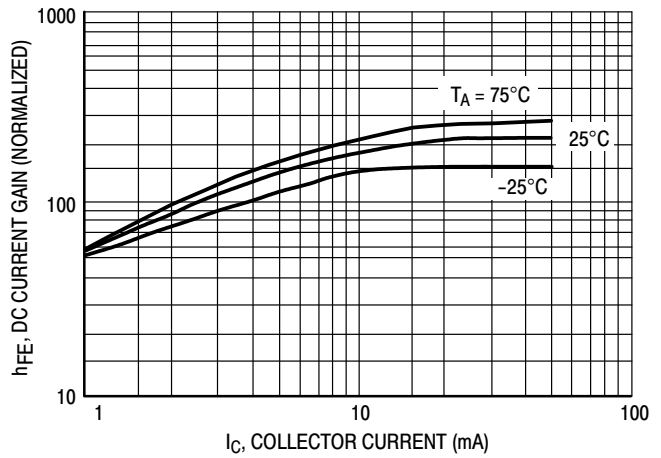
**Figure 17. Input Voltage versus Output Current**

**DTA114EET1 Series, SDTA114EET1 Series**

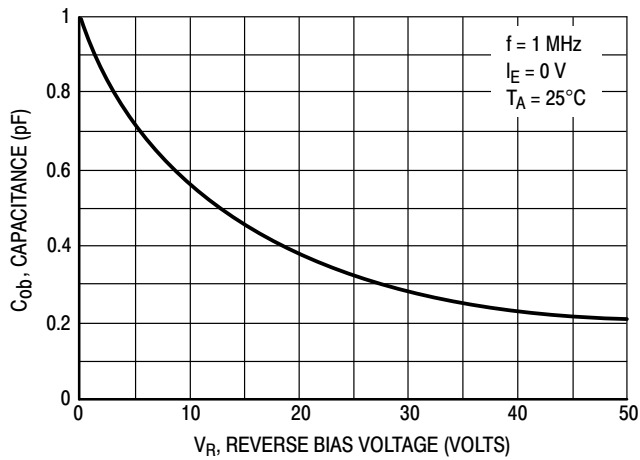
**TYPICAL ELECTRICAL CHARACTERISTICS - DTA144EET1**



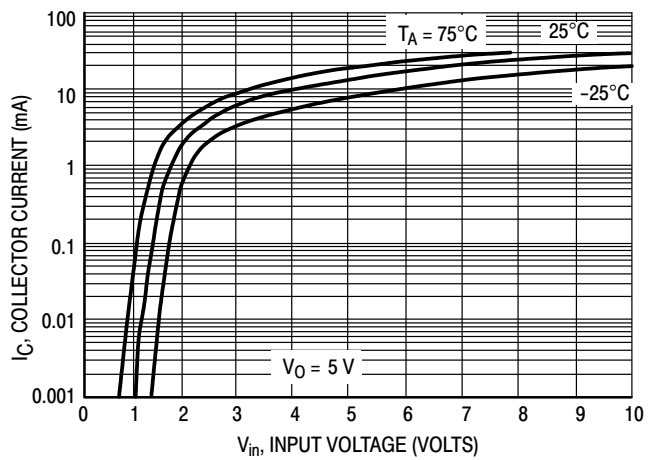
**Figure 18.  $V_{CE(sat)}$  versus  $I_C$**



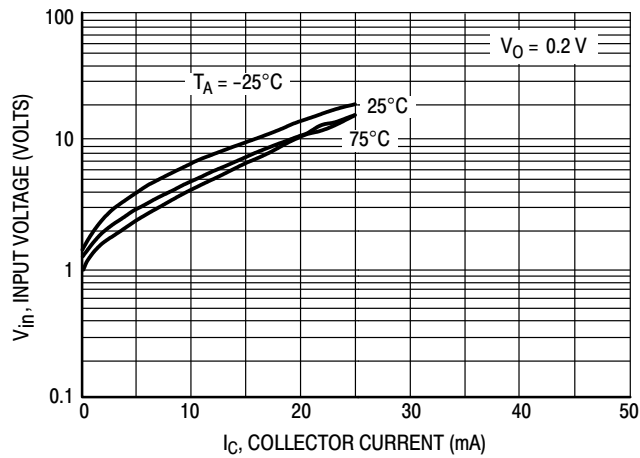
**Figure 19. DC Current Gain**



**Figure 20. Output Capacitance**



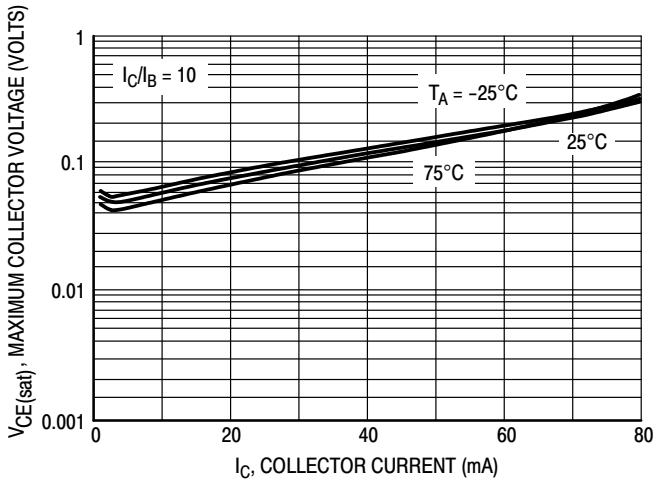
**Figure 21. Output Current versus Input Voltage**



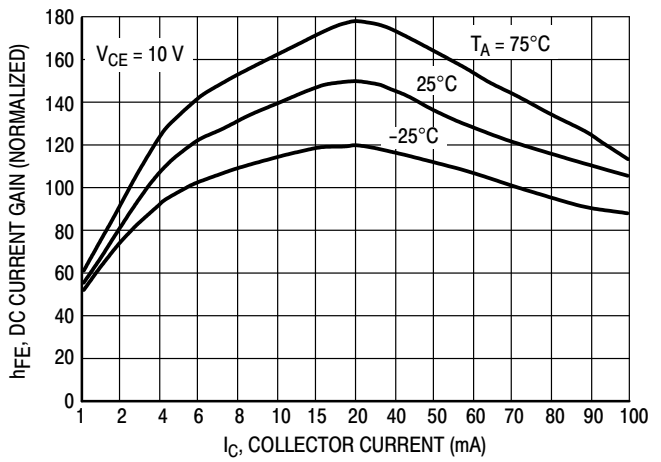
**Figure 22. Input Voltage versus Output Current**

**DTA114EET1 Series, SDTA114EET1 Series**

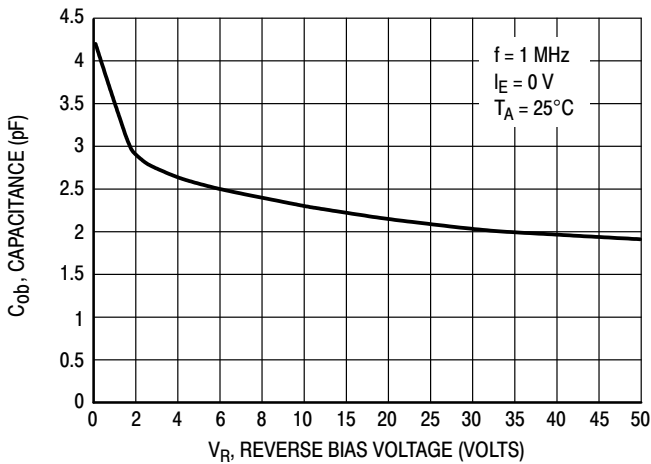
**TYPICAL ELECTRICAL CHARACTERISTICS – DTA114YET1, SDTA114YET1**



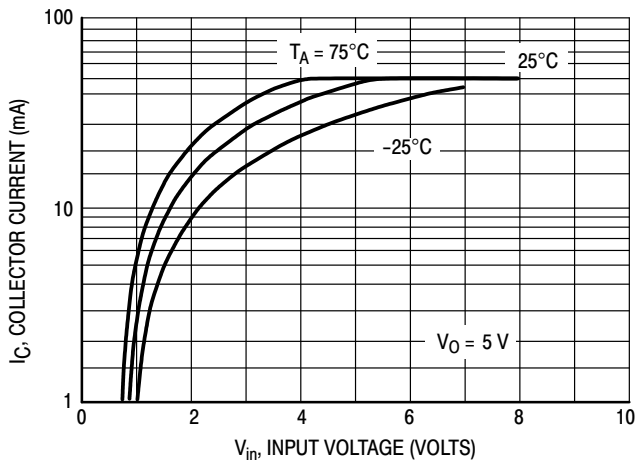
**Figure 23.  $V_{CE(sat)}$  versus  $I_C$**



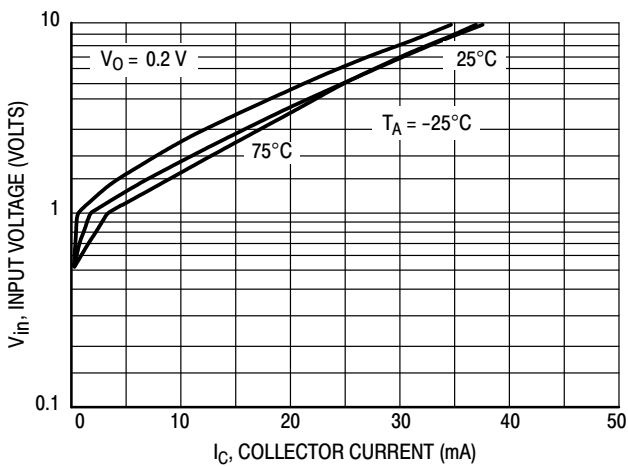
**Figure 24. DC Current Gain**



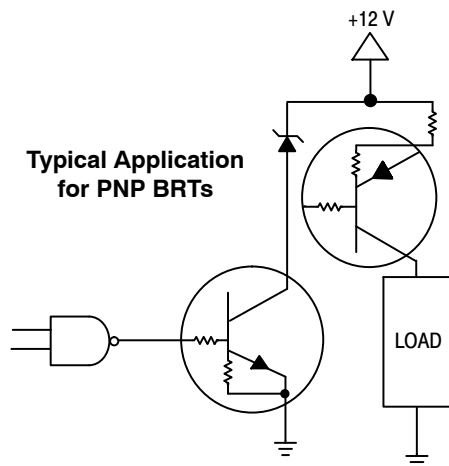
**Figure 25. Output Capacitance**



**Figure 26. Output Current versus Input Voltage**



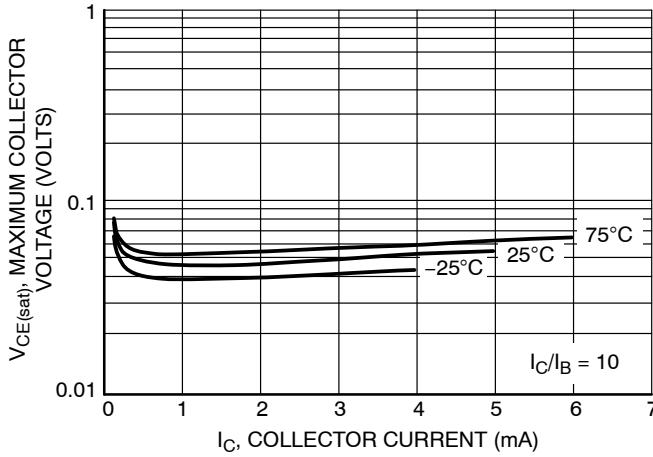
**Figure 27. Input Voltage versus Output Current**



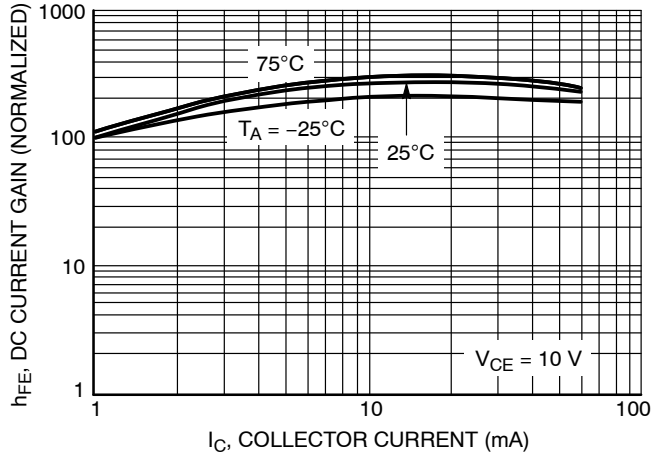
**Figure 28. Inexpensive, Unregulated Current Source**

**DTA114EET1 Series, SDTA114EET1 Series**

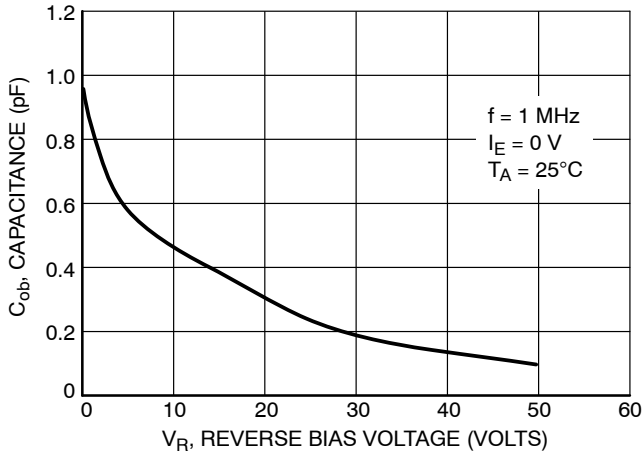
**TYPICAL ELECTRICAL CHARACTERISTICS — DTA115EET1**



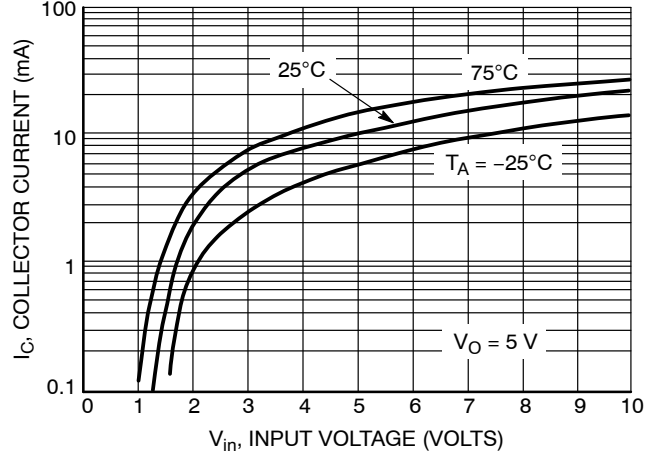
**Figure 29. Maximum Collector Voltage versus Collector Current**



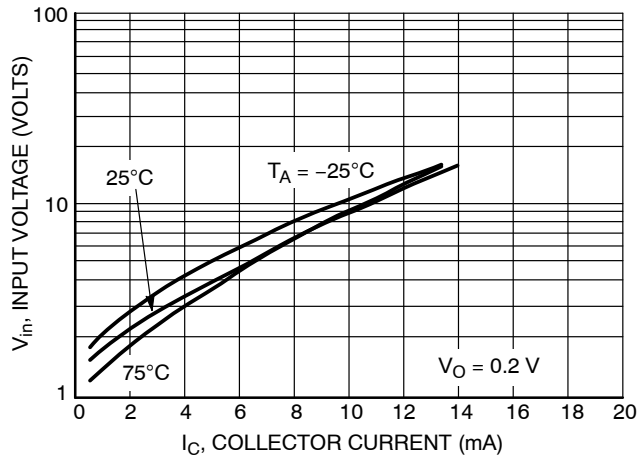
**Figure 30. DC Current Gain**



**Figure 31. Output Capacitance**



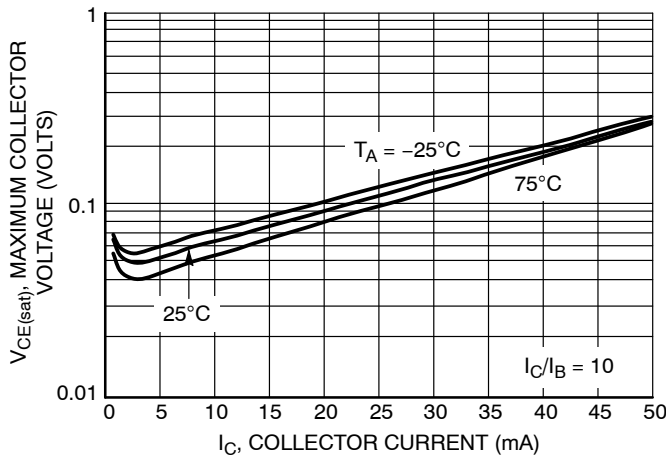
**Figure 32. Output Current versus Input Voltage**



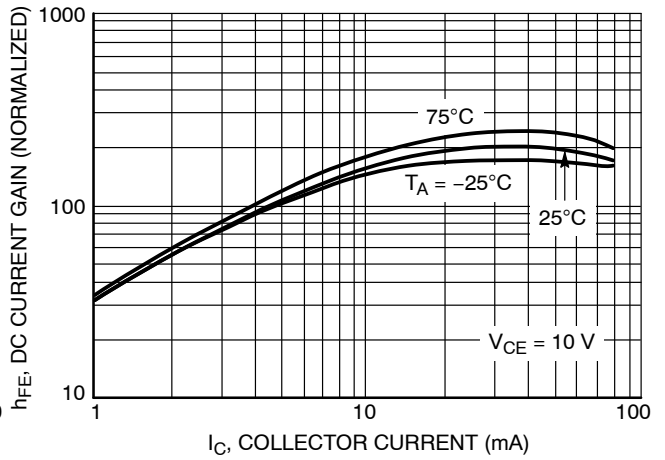
**Figure 33. Input Voltage versus Output Current**

**DTA114EET1 Series, SDTA114EET1 Series**

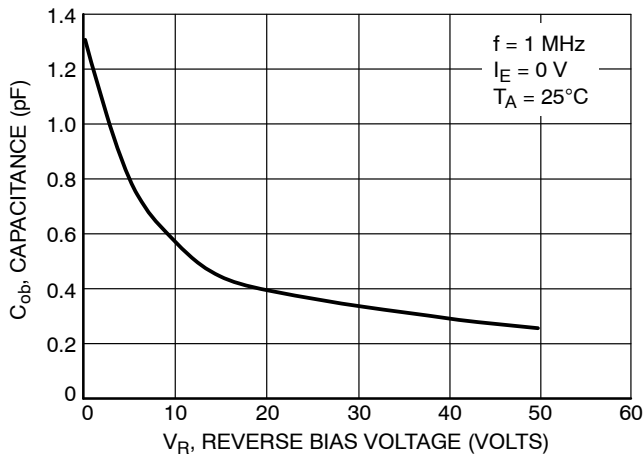
**TYPICAL ELECTRICAL CHARACTERISTICS — DTA144WET1**



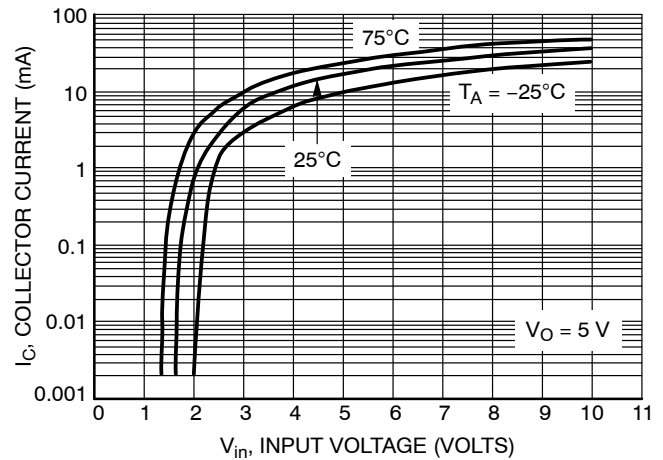
**Figure 34. Maximum Collector Voltage versus Collector Current**



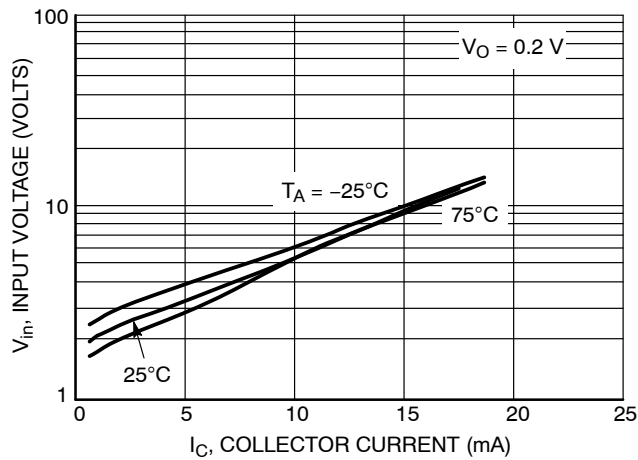
**Figure 35. DC Current Gain**



**Figure 36. Output Capacitance**



**Figure 37. Output Current versus Input Voltage**

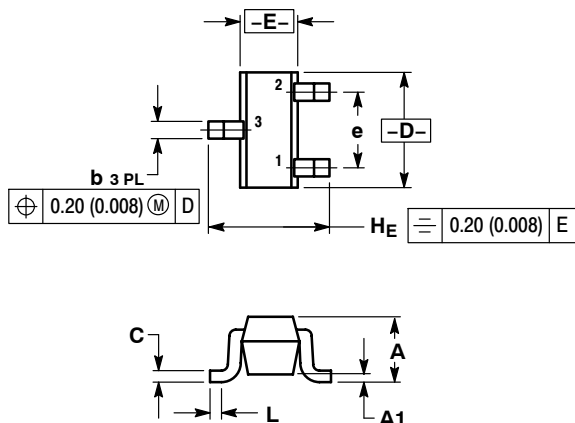


**Figure 38. Input Voltage versus Output Current**

**DTA114EET1 Series, SDTA114EET1 Series**

**PACKAGE DIMENSIONS**

**SC-75/SOT-416**  
**CASE 463-01**  
**ISSUE F**

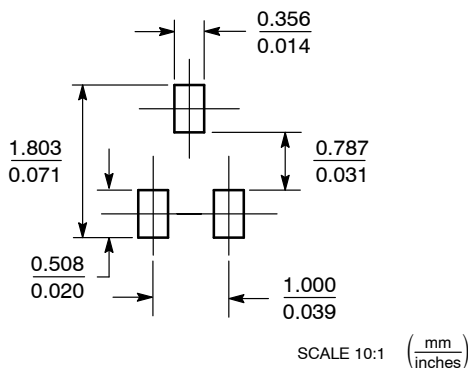


- NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
C	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
E	0.70	0.80	0.90	0.027	0.031	0.035
e	1.00 BSC			0.04 BSC		
L	0.10	0.15	0.20	0.004	0.006	0.008
H <sub>E</sub>	1.50	1.60	1.70	0.061	0.063	0.065

- STYLE 1:  
 PIN 1. BASE  
 2. EMITTER  
 3. COLLECTOR

**SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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